

## **isc** Silicon PNP Power Transistor

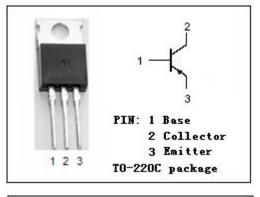
# 2SB919

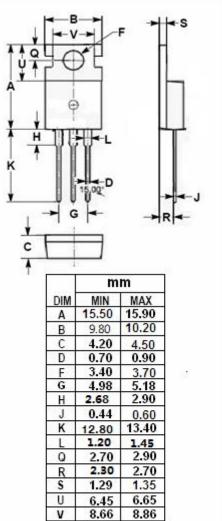
### DESCRIPTION

- High Collector Current: I<sub>C</sub>= -8A
- Low Collector Saturation Voltage
- : V<sub>CE(sat)</sub>= -0.5V(Max)@I<sub>C</sub>= -3A
- Complement to Type 2SD1235
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATIONS

Designed for large current switching applications.





## ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	-60	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	-30	V	
V <sub>EBO</sub>	Emitter-Base Voltage	-6	V	
lc	Collector Current-Continuous	-8	A	
I <sub>СМ</sub>	Collector Current-Peak	-15	A	
Pc	Total Power Dissipation @ T <sub>c</sub> =25℃	30	W	
	Total Power Dissipation @ T₂=25℃	1.75		
TJ	Junction Temperature	150	°C	
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C	



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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	Ic= -1mA; R <sub>BE</sub> = ∞	-30			V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = -1mA; I <sub>E</sub> = 0	-60			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = -1mA; I <sub>C</sub> = 0	-6			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -3Α; I <sub>B</sub> = -0.15Α			-0.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -40V; I <sub>E</sub> = 0			-0.1	mA
Іево	Emitter Cutoff Current	V <sub>EB</sub> = -4V; I <sub>C</sub> = 0			-0.1	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -1A; V <sub>CE</sub> = -2V	70		280	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -4A; V <sub>CE</sub> = -2V	30			
f⊤	Current-Gain—Bandwidth Product	Ic= -1A; Vce= -5V		120		MHz

#### h<sub>FE-1</sub> Classifications

Q	R	S
70-140	100-200	140-280

### NOTICE:

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